Low-power dual supply translating buffer Rev. 4 — 25 January 2022

1. General description

The 74AUP1T34-Q100 is a single dual supply translating buffer. Input A is referenced to V_{CC(A)} and output Y is referenced to V_{CC(Y)}. Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times. This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 1.1 V to 3.6 V. This device is fully specified for partial power down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)

 Specified from -40 °C to +85 °C and -40 °C to +125 °C
- Wide supply voltage range from 1.1 V to 3.6 V
- CMOS low power dissipation
- High noise immunity
- Complies with JEDEC standards:
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - MIL-STD-883, method 3015 Class 3A. Exceeds 5000 V
 - HBM JESD22-A114F Class 3A. Exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Wide supply voltage range:
 - V_{CC(A)}: 1.1 V to 3.6 V
 - V_{CC(Y)}: 1.1 V to 3.6 V
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Each port operates over the full 1.1 V to 3.6 V power supply range
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation

3. Ordering information

Table 1. Ordering information									
Type number	Package								
	Version								
74AUP1T34GW-Q100	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1					
74AUP1T34GM-Q100	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886					

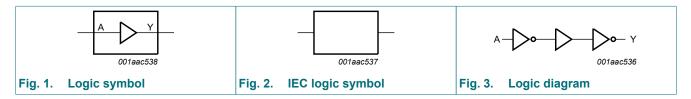
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4. Marking

Table 2. Marking	
Type number	Marking code[1]
74AUP1T34GW-Q100	pQ
74AUP1T34GM-Q100	pQ

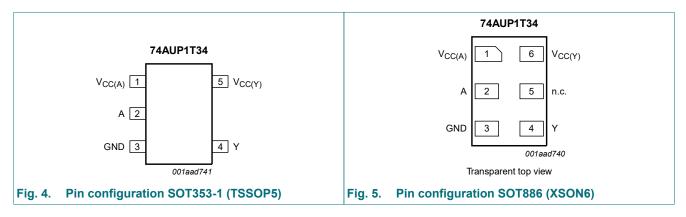
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1. Pinning



6.2. Pin description

Table 3. Pin description

Symbol	Pin	Pin			
	TSSOP5	XSON6			
V _{CC(A)}	1	1	supply voltage port A		
A	2	2	data input A		
GND	3	3	ground (0 V)		
Y	4	4	data output Y		
n.c.	-	5	not connected		
V _{CC(Y)}	5	6	supply voltage port Y		

7. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level.

Input	Output
A	Y
L	L
Н	Н

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC(A)}	supply voltage A		-0.5	+4.6	V
V _{CC(Y)}	supply voltage Y		-0.5	+4.6	V
I _{IK}	input clamping current	V ₁ < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
Ι _{ΟΚ}	output clamping current	V ₀ < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
lo	output current	$V_{O} = 0 V$ to $V_{CC(Y)}$	-	±20	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$ [2]	-	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT353-1 (TSSOP5) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

For SOT886 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC(A)}	supply voltage A		1.1	3.6	V
V _{CC(Y)}	supply voltage Y		1.1	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage		0	V _{CC(Y)}	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	control and data inputs; $V_{CC(A)} = 1.1 \text{ V to } 3.6 \text{ V}$	0	200	ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{IH}	HIGH-level	$V_{CC(A)}$ = 1.1 V to 1.95 V; $V_{CC(Y)}$ = 1.1 V to 3.6 V	$0.65 \times V_{CC(A)}$	-	-	V
	input voltage	$V_{CC(A)}$ = 2.3 V to 2.7 V; $V_{CC(Y)}$ = 1.1 V to 3.6 V	1.6	-	-	V
		$V_{CC(A)}$ = 3.0 V to 3.6 V; $V_{CC(Y)}$ = 1.1 V to 3.6 V	2.0	-	-	V
V _{IL}		$V_{CC(A)}$ = 1.1 V to 1.95 V; $V_{CC(Y)}$ = 1.1 V to 3.6 V	-	-	0.35 × V _{CC(A)}	V
	input voltage	$V_{CC(A)}$ = 2.3 V to 2.7 V; $V_{CC(Y)}$ = 1.1 V to 3.6 V	-	-	0.7	V
		$V_{CC(A)}$ = 3.0 V to 3.6 V; $V_{CC(Y)}$ = 1.1 V to 3.6 V	-	-	0.9	V
V _{OH}		V _I = V _{IH}				
	output voltage	I_{O} = -20 µA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 1.1 V to 3.6 V	V _{CC(Y)} - 0.1	-	-	V
01		I _O = -1.1 mA; V _{CC(A)} = V _{CC(Y)} = 1.1 V	0.75 × V _{CC(Y)}	-	-	V
		I _O = -1.7 mA; V _{CC(A)} = V _{CC(Y)} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC(A)} = V _{CC(Y)} = 1.65 V	1.32	-	-	V
		I_{O} = -2.3 mA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 2.3 V	2.05	-	-	V
		I_{O} = -3.1 mA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 2.3 V	1.9	-	-	V
		I_{O} = -2.7 mA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 3.0 V	2.72	-	-	V
		I_{O} = -4.0 mA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 3.0 V	2.6	-	-	V
V _{OL}		$V_{I} = V_{IL}$				
		I_{O} = 20 µA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 1.1 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC(A)} = V _{CC(Y)} = 1.1 V	-	-	$0.3 \times V_{CC(Y)}$	V
		I _O = 1.7 mA; V _{CC(A)} = V _{CC(Y)} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC(A)} = V _{CC(Y)} = 1.65 V	-	-	0.31	V
		I_{O} = 2.3 mA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC(A)} = V _{CC(Y)} = 2.3 V	-	-	0.44	V
		$I_{O} = 2.7 \text{ mA}; V_{CC(A)} = V_{CC(Y)} = 3.0 \text{ V}$	-	-	0.31	V
		I_{O} = 4.0 mA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 3.0 V	-	-	0.44	V
I		$V_{I} = 0 V \text{ to } 3.6 V; V_{CC(A)} = V_{CC(Y)} = 1.1 V \text{ to } 3.6 V$	-	-	±0.1	μA
I _{OFF}			-	-	±0.2	μA
			-	-	±0.2	μA
ΔI _{OFF}	additional power-off	A input; $V_1 = 0 V$ to 3.6 V; $V_{CC(A)} = 0 V$ to 0.2 V; $V_{CC(Y)} = 0 V$ to 3.6 V	-	-	±0.2	μA
	leakage current	Y output; $V_O = 0 V$ to 3.6 V; $V_{CC(A)} = 0 V$ to 3.6 V; $V_I = 0 V$ or 3.6 V; $V_{CC(Y)} = 0 V$ to 0.2 V	-	-	±0.2	μA

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CC}	supply current	port A; V_I = GND or $V_{CC(A)}$; I_O = 0 A				
		V _{CC(A)} = V _{CC(Y)} = 1.1 V to 3.6 V	-	-	0.5	μA
		V _{CC(A)} = 3.6 V; V _{CC(Y)} = 0 V	-	-	0.5	μA
		$V_{CC(A)} = 0 V; V_{CC(Y)} = 3.6 V$	-	0.0	-	μA
		port Y; $V_I = GND$ or $V_{CC(A)}$; $I_O = 0 A$				
		$V_{CC(A)} = V_{CC(Y)} = 1.1 \text{ V to } 3.6 \text{ V}$	-	-	0.5	μA
		V _{CC(A)} = 3.6 V; V _{CC(Y)} = 0 V	-	0.0	-	μA
		$V_{CC(A)} = 0 V; V_{CC(Y)} = 3.6 V$	-	-	0.5	μA
		port A and port Y; V_I = GND or $V_{CC(A)}$; I_O = 0 A; $V_{CC(A)} = V_{CC(Y)} = 1.1 V$ to 3.6 V	-	-	0.5	μA
ΔI _{CC}	additional supply current	A input; $V_{CC(A)} = 3.3 \text{ V}$; $V_{CC(Y)} = 0 \text{ V}$ to 3.6 V; $V_I = V_{CC(A)} - 0.6 \text{ V}$	-	-	40	μA
CI	input capacitance	A input; $V_{CC(A)} = V_{CC(Y)} = 0$ V to 3.6 V; V _I = GND or $V_{CC(A)}$	-	1.0	-	pF
Co	output capacitance	Y output; $V_O = GND$; $V_{CC(Y)} = 0 V$; $V_{CC(A)} = 0 V$ to 3.6 V	-	1.8	-	pF
T _{amb} = -	40 °C to +85 °C					
VIH	HIGH-level	$V_{CC(A)}$ = 1.1 V to 1.95 V; $V_{CC(Y)}$ = 1.1 V to 3.6 V	0.65 × V _{CC(A)}	-	-	V
	input voltage	$V_{CC(A)}$ = 2.3 V to 2.7 V; $V_{CC(Y)}$ = 1.1 V to 3.6 V	1.6	-	-	V
		$V_{CC(A)}$ = 3.0 V to 3.6 V; $V_{CC(Y)}$ = 1.1 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level	$V_{CC(A)}$ = 1.1 V to 1.95 V; $V_{CC(Y)}$ = 1.1 V to 3.6 V	-	-	$0.35 \times V_{CC(A)}$	V
	input voltage	$V_{CC(A)}$ = 2.3 V to 2.7 V; $V_{CC(Y)}$ = 1.1 V to 3.6 V	-	-	0.7	V
		$V_{CC(A)}$ = 3.0 V to 3.6 V; $V_{CC(Y)}$ = 1.1 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level	V _I = V _{IH}				
	output voltage	I_{O} = -20 µA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 1.1 V to 3.6 V	V _{CC(Y)} - 0.1	-	-	V
		I_{O} = -1.1 mA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 1.1 V	$0.7 \times V_{CC(Y)}$	-	-	V
		I_{O} = -1.7 mA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC(A)} = V _{CC(Y)} = 1.65 V	1.30	-	-	V
		I_{O} = -2.3 mA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 2.3 V	1.97	-	-	V
		I_{O} = -3.1 mA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 2.3 V	1.85	-	-	V
		I_{O} = -2.7 mA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 3.0 V	2.67	-	-	V
		I_{O} = -4.0 mA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level	$V_{I} = V_{IL}$				
	output voltage	I_{O} = 20 µA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 1.1 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC(A)} = V _{CC(Y)} = 1.1 V	-	-	$0.3 \times V_{CC(Y)}$	V
		I _O = 1.7 mA; V _{CC(A)} = V _{CC(Y)} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC(A)} = V _{CC(Y)} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC(A)} = V _{CC(Y)} = 2.3 V	-	-	0.33	V
		I_{O} = 3.1 mA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC(A)} = V _{CC(Y)} = 3.0 V	-	-	0.33	V
		$I_{O} = 4.0 \text{ mA}; V_{CC(A)} = V_{CC(Y)} = 3.0 \text{ V}$	-	-	0.45	V

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
lı	input leakage current	$V_{I} = 0 V \text{ to } 3.6 V; V_{CC(A)} = V_{CC(Y)} = 1.1 V \text{ to } 3.6 V$	-	-	±0.5	μA
I _{OFF}	power-off leakage current	A input; $V_I = 0 V$ to 3.6 V; $V_{CC(A)} = 0 V$; $V_{CC(Y)} = 0 V$ to 3.6 V	-	-	±0.5	μA
		Y output; V _O = 0 V to 3.6 V; V _{CC(A)} = 0 V to 3.6 V; V _I = 0 V or 3.6 V; V _{CC(Y)} = 0 V	-	-	±0.5	μA
∆I _{OFF}	additional power-off	A input; $V_I = 0 V$ to 3.6 V; $V_{CC(A)} = 0 V$ to 0.2 V; $V_{CC(Y)} = 0 V$ to 3.6 V	-	-	±0.6	μA
	leakage current	Y output; $V_O = 0 V$ to 3.6 V; $V_{CC(A)} = 0 V$ to 3.6 V; $V_I = 0 V$ or 3.6 V; $V_{CC(Y)} = 0 V$ to 0.2 V	-	-	±0.6	μA
I _{CC}	supply current	port A; V_I = GND or $V_{CC(A)}$; I_O = 0 A				
		$V_{CC(A)} = V_{CC(Y)} = 1.1 \text{ V to } 3.6 \text{ V}$	-	-	0.9	μA
		$V_{CC(A)} = 3.6 \text{ V}; V_{CC(Y)} = 0 \text{ V}$	-	-	0.9	μA
		V _{CC(A)} = 0 V; V _{CC(Y)} = 3.6 V	-	0.0	-	μA
		port Y; V_I = GND or $V_{CC(A)}$; I_O = 0 A				
		V _{CC(A)} = V _{CC(Y)} = 1.1 V to 3.6 V	-	-	0.9	μA
		V _{CC(A)} = 3.6 V; V _{CC(Y)} = 0 V	-	0.0	-	μA
		V _{CC(A)} = 0 V; V _{CC(Y)} = 3.6 V	-	-	0.9	μA
		port A and port Y; V_I = GND or $V_{CC(A)}$; I_O = 0 A; $V_{CC(A)} = V_{CC(Y)} = 1.1 \text{ V}$ to 3.6 V	-	-	0.9	μA
ΔI _{CC}	additional supply current	A input; $V_{CC(A)} = 3.3 \text{ V}$; $V_{CC(Y)} = 0 \text{ V}$ to 3.6 V; $V_1 = V_{CC(A)} - 0.6 \text{ V}$	-	-	50	μA
T _{amb} = -4	40 °C to +125 °C					
V _{IH}	HIGH-level	$V_{CC(A)}$ = 1.1 V to 1.95 V; $V_{CC(Y)}$ = 1.1 V to 3.6 V	$0.7 \times V_{CC(A)}$	-	-	V
	input voltage	$V_{CC(A)}$ = 2.3 V to 2.7 V; $V_{CC(Y)}$ = 1.1 V to 3.6 V	1.6	-	-	V
		$V_{CC(A)}$ = 3.0 V to 3.6 V; $V_{CC(Y)}$ = 1.1 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level	$V_{CC(A)}$ = 1.1 V to 1.95 V; $V_{CC(Y)}$ = 1.1 V to 3.6 V	-	-	$0.3 \times V_{CC(A)}$	V
	input voltage	V _{CC(A)} = 2.3 V to 2.7 V; V _{CC(Y)} = 1.1 V to 3.6 V	-	-	0.7	V
		V _{CC(A)} = 3.0 V to 3.6 V; V _{CC(Y)} = 1.1 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level	V _I = V _{IH}				
	output voltage	I_{O} = -20 µA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 1.1 V to 3.6 V	V _{CC(Y)} - 0.11	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC(A)} = V_{CC(Y)} = 1.1 \text{ V}$		-	-	V
		I _O = -1.7 mA; V _{CC(A)} = V _{CC(Y)} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC(A)} = V _{CC(Y)} = 1.65 V	1.17	-	-	V
		I_{O} = -2.3 mA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 2.3 V	1.77	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC(A)} = V_{CC(Y)} = 2.3 \text{ V}$	1.67	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC(A)} = V_{CC(Y)} = 3.0 \text{ V}$	2.40	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC(A)} = V_{CC(Y)} = 3.0 \text{ V}$	2.30	-	-	V

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OL}	LOW-level	V _I = V _{IL}				
	output voltage	I_{O} = 20 µA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 1.1 V to 3.6 V	-	-	0.11	V
		I_{O} = 1.1 mA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 1.1 V	-	-	$0.33 \times V_{CC(Y)}$	V
		I_{O} = 1.7 mA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC(A)} = V _{CC(Y)} = 1.65 V	-	-	0.39	V
		I_{O} = 2.3 mA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 2.3 V	-	-	0.36	V
		$I_{O} = 3.1 \text{ mA}; V_{CC(A)} = V_{CC(Y)} = 2.3 \text{ V}$	-	-	0.50	V
		I_{O} = 2.7 mA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 3.0 V	-	-	0.36	V
		I_{O} = 4.0 mA; $V_{CC(A)}$ = $V_{CC(Y)}$ = 3.0 V	-	-	0.50	V
l _l	input leakage current	$V_1 = 0 V \text{ to } 3.6 V; V_{CC(A)} = V_{CC(Y)} = 1.1 V \text{ to } 3.6 V$	-	-	±0.75	μA
I _{OFF}	power-off leakage current	A input; $V_1 = 0 V$ to 3.6 V; $V_{CC(A)} = 0 V$; $V_{CC(Y)} = 0 V$ to 3.6 V	-	-	±0.75	μA
		Y output; $V_O = 0 V$ to 3.6 V; $V_{CC(A)} = 0 V$ to 3.6 V; $V_I = 0 V$ or 3.6 V; $V_{CC(Y)} = 0 V$	-	-	±0.75	μA
ΔI _{OFF}	additional power-off	A input; $V_I = 0 V$ to 3.6 V; $V_{CC(A)} = 0 V$ to 0.2 V; $V_{CC(Y)} = 0 V$ to 3.6 V	-	-	±0.75	μA
	leakage current	Y output; $V_O = 0 V$ to 3.6 V; $V_{CC(A)} = 0 V$ to 3.6 V; $V_I = 0 V$ or 3.6 V; $V_{CC(Y)} = 0 V$ to 0.2 V	-	-	±0.75	μA
I _{CC}	supply current	port A; V_I = GND or $V_{CC(A)}$; I_O = 0 A				
		$V_{CC(A)} = V_{CC(Y)} = 1.1 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μA
		V _{CC(A)} = 3.6 V; V _{CC(Y)} = 0 V	-	-	1.4	μA
		V _{CC(A)} = 0 V; V _{CC(Y)} = 3.6 V	-	0.0	-	μA
		port Y; V_1 = GND or $V_{CC(A)}$; I_0 = 0 A				
		$V_{CC(A)} = V_{CC(Y)} = 1.1 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μA
		V _{CC(A)} = 3.6 V; V _{CC(Y)} = 0 V	-	0.0	-	μA
		V _{CC(A)} = 0 V; V _{CC(Y)} = 3.6 V	-	-	1.4	μA
		port A and port Y; V_I = GND or $V_{CC(A)}$; I_O = 0 A; $V_{CC(A)} = V_{CC(Y)} = 1.1 V$ to 3.6 V	-	-	1.4	μA
ΔI _{CC}	additional supply current	A input; $V_{CC(A)} = 3.3 \text{ V}$; $V_{CC(Y)} = 0 \text{ V}$ to 3.6 V; $V_1 = V_{CC(A)} - 0.6 \text{ V}$	-	-	75	μA

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 7.

Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	-40 °C to	o +125 ℃	Unit
			Min	Typ[1]	Мах	Min	Max	Min	Max	
C _L = 5 p	F; V _{CC(A)} = 1.1	V to 1.3 V							1	
t _{pd}	propagation	A to Y; see <u>Fig. 6</u> [2]								
	delay	V _{CC(Y)} = 1.1 V to 1.3 V	2.6	9.8	25.4	2.3	25.9	2.3	25.9	ns
		V _{CC(Y)} = 1.4 V to 1.6 V	2.4	7.1	15.3	2.2	16.3	2.2	16.7	ns
		V _{CC(Y)} = 1.65 V to 1.95 V	2.1	6.0	12.7	1.9	13.8	1.9	14.3	ns
		V _{CC(Y)} = 2.3 V to 2.7 V	2.0	5.1	9.8	2.0	10.5	2.0	10.9	ns
		V _{CC(Y)} = 3.0 V to 3.6 V	2.1	4.7	8.8	1.9	9.1	1.9	9.3	ns
C _L = 5 p	F; V _{CC(A)} = 1.4	V to 1.6 V							1	
t _{pd}	propagation	A to Y; see Fig. 6 [2]								
	delay	V _{CC(Y)} = 1.1 V to 1.3 V	2.3	9.1	23.9	2.0	24.5	2.0	24.5	ns
		V _{CC(Y)} = 1.4 V to 1.6 V	2.1	6.4	13.6	1.9	14.7	1.9	15.2	ns
		V _{CC(Y)} = 1.65 V to 1.95 V	1.8	5.3	10.9	1.6	12.1	1.6	12.6	ns
		V _{CC(Y)} = 2.3 V to 2.7 V	1.7	4.3	7.8	1.6	8.7	1.6	9.2	ns
		V _{CC(Y)} = 3.0 V to 3.6 V	1.8	3.9	6.6	1.6	7.1	1.6	7.5	ns
C _L = 5 p	F; V _{CC(A)} = 1.6	5 V to 1.95 V							1	
t _{pd}	propagation delay	A to Y; see Fig. 6 [2]								
		V _{CC(Y)} = 1.1 V to 1.3 V	2.2	8.8	23.2	1.9	23.9	1.9	24.0	ns
		V _{CC(Y)} = 1.4 V to 1.6 V	2.0	6.0	13.0	1.8	14.1	1.8	14.6	ns
		V _{CC(Y)} = 1.65 V to 1.95 V	1.8	4.9	10.3	1.5	11.4	1.5	12.0	ns
		V _{CC(Y)} = 2.3 V to 2.7 V	1.6	3.9	7.2	1.5	8.0	1.5	8.5	ns
		V _{CC(Y)} = 3.0 V to 3.6 V	1.7	3.5	5.9	1.5	6.4	1.5	6.8	ns
C _L = 5 p	F; V _{CC(A)} = 2.3	V to 2.7 V								
t _{pd}	propagation	A to Y; see Fig. 6 [2]								
	delay	V _{CC(Y)} = 1.1 V to 1.3 V	2.2	8.4	22.8	1.9	23.4	1.9	23.4	ns
		V _{CC(Y)} = 1.4 V to 1.6 V	1.9	5.7	12.3	1.8	13.4	1.8	14.0	ns
		V _{CC(Y)} = 1.65 V to 1.95 V	1.7	4.6	9.6	1.5	10.7	1.5	11.2	ns
		V _{CC(Y)} = 2.3 V to 2.7 V	1.5	3.5	6.3	1.5	7.2	1.5	7.7	ns
		V _{CC(Y)} = 3.0 V to 3.6 V	1.6	3.1	5.1	1.4	5.6	1.4	6.0	ns
C _L = 5 p	F; V _{CC(A)} = 3.0	V to 3.6 V								
t _{pd}	propagation	A to Y; see <u>Fig. 6</u> [2]								
	delay	V _{CC(Y)} = 1.1 V to 1.3 V	2.2	8.1	22.5	1.9	22.9	1.9	22.9	ns
		V _{CC(Y)} = 1.4 V to 1.6 V	1.9	5.4	12.0	1.8	12.9	1.8	13.4	ns
		V _{CC(Y)} = 1.65 V to 1.95 V	1.7	4.3	9.2	1.5	10.2	1.5	10.7	ns
		V _{CC(Y)} = 2.3 V to 2.7 V	1.5	3.3	6.0	1.5	6.7	1.5	7.2	ns
		V _{CC(Y)} = 3.0 V to 3.6 V	1.6	2.9	4.8	1.4	5.2	1.4	5.5	ns

Product data sheet

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _L = 10	pF; V _{CC(A)} = 1.	1 V to 1.3 V		1						
t _{pd}	propagation	A to Y; see Fig. 6 [2]								
de	delay	V _{CC(Y)} = 1.1 V to 1.3 V	2.6	10.7	27.1	2.5	27.6	2.5	27.6	ns
		V _{CC(Y)} = 1.4 V to 1.6 V	2.6	7.7	16.7	2.3	17.5	2.3	17.6	ns
		V _{CC(Y)} = 1.65 V to 1.95 V	2.7	6.6	13.4	2.4	14.2	2.4	14.7	ns
		V _{CC(Y)} = 2.3 V to 2.7 V	2.2	5.6	10.3	2.2	11.0	2.2	11.4	ns
		V _{CC(Y)} = 3.0 V to 3.6 V	2.5	5.3	9.5	2.2	9.7	2.2	10.0	ns
C _L = 10	pF; V _{CC(A)} = 1.	4 V to 1.6 V								
t _{pd}	propagation	A to Y; see <u>Fig. 6</u> [2]								
	delay	V _{CC(Y)} = 1.1 V to 1.3 V	2.4	10.0	25.6	2.2	26.1	2.2	26.1	ns
		V _{CC(Y)} = 1.4 V to 1.6 V	2.4	7.0	15.0	2.0	15.8	2.0	16.4	ns
		V _{CC(Y)} = 1.65 V to 1.95 V	2.4	5.9	11.6	2.1	12.5	2.1	13.1	ns
		V _{CC(Y)} = 2.3 V to 2.7 V	2.0	4.8	8.4	1.9	9.2	1.9	9.7	ns
		V _{CC(Y)} = 3.0 V to 3.6 V	2.2	4.4	7.4	1.9	7.7	1.9	8.1	ns
C _L = 10	pF; V _{CC(A)} = 1.	65 V to 1.95 V								
t _{pd}	propagation delay	A to Y; see <u>Fig. 6</u> [2]								
		V _{CC(Y)} = 1.1 V to 1.3 V	2.3	9.7	24.8	2.1	25.5	2.1	25.7	ns
		V _{CC(Y)} = 1.4 V to 1.6 V	2.3	6.6	14.3	2.0	15.3	2.0	15.8	ns
		V _{CC(Y)} = 1.65 V to 1.95 V	2.3	5.5	11.0	2.0	11.9	2.0	12.5	ns
		V _{CC(Y)} = 2.3 V to 2.7 V	1.9	4.4	7.7	1.8	8.6	1.8	9.0	ns
		V _{CC(Y)} = 3.0 V to 3.6 V	2.1	4.0	6.6	1.8	7.1	1.8	7.4	ns
C _L = 10	pF; V _{CC(A)} = 2.	3 V to 2.7 V								
t _{pd}	propagation	A to Y; see <u>Fig. 6</u> [2]								
	delay	V _{CC(Y)} = 1.1 V to 1.3 V	2.3	9.3	24.4	2.1	25.1	2.1	25.1	ns
		V _{CC(Y)} = 1.4 V to 1.6 V	2.2	6.3	13.6	1.9	14.6	1.9	15.1	ns
		V _{CC(Y)} = 1.65 V to 1.95 V	2.2	5.1	10.3	2.0	11.2	2.0	11.7	ns
		V _{CC(Y)} = 2.3 V to 2.7 V	1.8	4.1	6.9	1.8	7.7	1.8	8.2	ns
		V _{CC(Y)} = 3.0 V to 3.6 V	2.0	3.6	5.8	1.7	6.3	1.7	6.6	ns
C _L = 10	pF; V _{CC(A)} = 3.	0 V to 3.6 V								
t _{pd}	propagation	A to Y; see <u>Fig. 6</u> [2]								
	delay	V _{CC(Y)} = 1.1 V to 1.3 V	2.3	9.0	24.2	2.1	24.6	2.1	24.6	ns
		V _{CC(Y)} = 1.4 V to 1.6 V	2.2	6.0	13.3	1.9	14.1	1.9	14.6	ns
		V _{CC(Y)} = 1.65 V to 1.95 V	2.2	4.9	9.9	2.0	10.6	2.0	11.2	ns
		V _{CC(Y)} = 2.3 V to 2.7 V	1.8	3.9	6.5	1.8	7.3	1.8	7.7	ns
		V _{CC(Y)} = 3.0 V to 3.6 V	2.0	3.5	5.4	1.7	5.8	1.7	6.2	ns

Low-power dual supply translating buffer

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _L = 15	pF; V _{CC(A)} = 1.	1 V to 1.3 V								
t _{pd}	propagation	A to Y; see <u>Fig. 6</u> [2]								
	delay	V _{CC(Y)} = 1.1 V to 1.3 V	3.0	11.5	28.6	2.8	29.2	2.8	29.2	ns
		V _{CC(Y)} = 1.4 V to 1.6 V	3.1	8.3	17.3	2.7	18.6	2.7	19.1	ns
		V _{CC(Y)} = 1.65 V to 1.95 V	2.8	7.1	14.1	2.7	15.2	2.7	15.8	ns
		V _{CC(Y)} = 2.3 V to 2.7 V	2.6	6.1	11.1	2.7	11.6	2.7	12.1	ns
		V _{CC(Y)} = 3.0 V to 3.6 V	2.9	5.7	9.9	2.6	10.3	2.6	10.6	ns
C _L = 15	pF; V _{CC(A)} = 1.	4 V to 1.6 V								
t _{pd}	propagation	A to Y; see Fig. 6 [2]								
	delay	V _{CC(Y)} = 1.1 V to 1.3 V	2.8	10.8	27.1	2.6	27.7	2.6	27.7	ns
		V _{CC(Y)} = 1.4 V to 1.6 V	2.8	7.6	15.7	2.4	17.0	2.4	17.6	ns
		V _{CC(Y)} = 1.65 V to 1.95 V	2.5	6.3	12.3	2.4	13.5	2.4	14.1	ns
		V _{CC(Y)} = 2.3 V to 2.7 V	2.3	5.3	9.2	2.4	9.9	2.4	10.3	ns
		V _{CC(Y)} = 3.0 V to 3.6 V	2.6	4.9	7.8	2.3	8.3	2.3	8.7	ns
C _L = 15	pF; V _{CC(A)} = 1.	65 V to 1.95 V							_	
t _{pd}	propagation delay	A to Y; see <u>Fig. 6</u> [2]								
		V _{CC(Y)} = 1.1 V to 1.3 V	2.7	10.5	26.4	2.5	27.1	2.5	27.3	ns
		V _{CC(Y)} = 1.4 V to 1.6 V	2.7	7.2	15.0	2.3	16.4	2.3	17.0	ns
		V _{CC(Y)} = 1.65 V to 1.95 V	2.4	6.0	11.7	2.3	12.8	2.3	13.5	ns
		V _{CC(Y)} = 2.3 V to 2.7 V	2.2	4.9	8.5	2.2	9.2	2.2	9.7	ns
		V _{CC(Y)} = 3.0 V to 3.6 V	2.5	4.5	7.1	2.2	7.7	2.2	8.0	ns
C _L = 15	pF; V _{CC(A)} = 2.	3 V to 2.7 V							_	
t _{pd}	propagation	A to Y; see Fig. 6 [2]								
	delay	V _{CC(Y)} = 1.1 V to 1.3 V	2.6	10.1	26.0	2.4	26.7	2.4	26.7	ns
		V _{CC(Y)} = 1.4 V to 1.6 V	2.7	6.9	14.3	2.3	15.7	2.3	16.3	ns
		V _{CC(Y)} = 1.65 V to 1.95 V	2.4	5.6	10.9	2.2	12.1	2.2	12.7	ns
		V _{CC(Y)} = 2.3 V to 2.7 V	2.1	4.5	7.6	2.2	8.4	2.2	8.9	ns
		V _{CC(Y)} = 3.0 V to 3.6 V	2.4	4.1	6.2	2.1	6.8	2.1	7.2	ns
C _L = 15	pF; V _{CC(A)} = 3.	0 V to 3.6 V							-	
t _{pd}	propagation	A to Y; see <u>Fig. 6</u> [2]								
	delay	V _{CC(Y)} = 1.1 V to 1.3 V	2.6	9.8	25.7	2.4	26.2	2.4	26.2	ns
		V _{CC(Y)} = 1.4 V to 1.6 V	2.7	6.6	14.0	2.3	15.2	2.3	15.7	ns
		V _{CC(Y)} = 1.65 V to 1.95 V	2.4	5.4	10.5	2.2	11.6	2.2	12.1	ns
		V _{CC(Y)} = 2.3 V to 2.7 V	2.1	4.3	7.3	2.2	7.9	2.2	8.4	ns
		V _{CC(Y)} = 3.0 V to 3.6 V	2.4	3.9	5.9	2.1	6.4	2.1	6.8	ns

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Low-power dual supply translating buffer

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _L = 30	pF; V _{CC(A)} = 1.	1 V to 1.3 V								
t _{pd}	propagation	A to Y; see <u>Fig. 6</u> [2]								
	delay	V _{CC(Y)} = 1.1 V to 1.3 V	3.7	13.7	32.9	3.5	33.5	3.5	33.5	ns
		V _{CC(Y)} = 1.4 V to 1.6 V	3.6	9.8	19.5	3.6	20.9	3.6	21.4	ns
		V _{CC(Y)} = 1.65 V to 1.95 V	3.7	8.4	15.9	3.5	17.0	3.5	17.7	ns
		V _{CC(Y)} = 2.3 V to 2.7 V	3.0	7.2	12.2	3.4	12.7	3.4	13.2	ns
		V _{CC(Y)} = 3.0 V to 3.6 V	3.8	6.8	10.9	3.4	12.2	3.4	12.5	ns
C _L = 30	pF; V _{CC(A)} = 1.	4 V to 1.6 V							_	
t _{pd}	propagation	A to Y; see <u>Fig. 6</u> [2]								
	delay	V _{CC(Y)} = 1.1 V to 1.3 V	3.5	13.1	31.5	3.2	32.0	3.2	32.0	ns
		V _{CC(Y)} = 1.4 V to 1.6 V	3.3	9.1	17.8	3.3	19.2	3.3	19.9	ns
		V _{CC(Y)} = 1.65 V to 1.95 V	3.4	7.6	14.2	3.2	15.4	3.2	16.0	ns
		V _{CC(Y)} = 2.3 V to 2.7 V	2.8	6.4	10.3	3.1	11.0	3.1	11.5	ns
		V _{CC(Y)} = 3.0 V to 3.6 V	3.5	5.9	8.9	3.1	10.1	3.1	10.5	ns
C _L = 30	pF; V _{CC(A)} = 1.	65 V to 1.95 V							-	
t _{pd}	propagation delay	A to Y; see <u>Fig. 6</u> [2]								
		V _{CC(Y)} = 1.1 V to 1.3 V	3.4	12.7	30.7	3.1	31.5	3.1	31.5	ns
		V _{CC(Y)} = 1.4 V to 1.6 V	3.2	8.8	17.2	3.2	18.7	3.2	19.3	ns
		V _{CC(Y)} = 1.65 V to 1.95 V	3.3	7.3	13.5	3.1	14.7	3.1	15.4	ns
		V _{CC(Y)} = 2.3 V to 2.7 V	2.7	6.0	9.6	3.0	10.4	3.0	10.9	ns
		V _{CC(Y)} = 3.0 V to 3.6 V	3.4	5.6	8.2	2.9	9.4	2.9	9.8	ns
C _L = 30	pF; V _{CC(A)} = 2.	3 V to 2.7 V							-	
t _{pd}	propagation	A to Y; see <u>Fig. 6</u> [2]								
	delay	V _{CC(Y)} = 1.1 V to 1.3 V	3.3	12.4	30.3	3.1	31.0	3.1	31.0	ns
		V _{CC(Y)} = 1.4 V to 1.6 V	3.2	8.4	16.5	3.1	18.0	3.1	18.7	ns
		V _{CC(Y)} = 1.65 V to 1.95 V	3.2	6.9	12.8	3.0	14.0	3.0	14.6	ns
		V _{CC(Y)} = 2.3 V to 2.7 V	2.6	5.6	8.8	2.9	9.6	2.9	10.1	ns
		V _{CC(Y)} = 3.0 V to 3.6 V	3.3	5.2	7.3	2.9	8.5	2.9	9.0	ns
C _L = 30	pF; V _{CC(A)} = 3.	0 V to 3.6 V								
t _{pd}	propagation	A to Y; see <u>Fig. 6</u> [2]								
	delay	V _{CC(Y)} = 1.1 V to 1.3 V	3.3	12.0	30.0	3.1	30.5	3.1	30.5	ns
		V _{CC(Y)} = 1.4 V to 1.6 V	3.2	8.1	16.2	3.1	17.5	3.1	18.1	ns
		V _{CC(Y)} = 1.65 V to 1.95 V	3.2	6.7	12.4	3.0	13.4	3.0	14.1	ns
		V _{CC(Y)} = 2.3 V to 2.7 V	2.6	5.5	8.5	2.9	9.1	2.9	9.6	ns
		V _{CC(Y)} = 3.0 V to 3.6 V	3.2	5.0	7.0	2.9	8.1	2.9	8.5	ns

Low-power dual supply translating buffer

Symbol	Parameter	Conditions	25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit	
			Min	Typ[1]	Max	Min	Max	Min	Max	1
C _L = 5 p	F, 10 pF, 15 pF	and 30 pF							1	
(power dissipation capacitance									
		$V_{CC(A)} = V_{CC(Y)} = 1.2 V$	-	3.8	-	-	-	-	-	pF
		V _{CC(A)} = V _{CC(Y)} = 1.5 V	-	3.8	-	-	-	-	-	pF
		V _{CC(A)} = V _{CC(Y)} = 1.8 V	-	4.1	-	-	-	-	-	pF
		$V_{CC(A)} = V_{CC(Y)} = 2.5 V$	-	4.2	-	-	-	-	-	pF
		$V_{CC(A)} = V_{CC(Y)} = 3.3 V$	-	4.6	-	-	-	-	-	pF

[1] [2] All typical values are measured at nominal V_{CC} .

 t_{pd} is the same as t_{PLH} and t_{PHL} . All specified values are the average typical values over all stated loads. [3]

[4] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 f_o = output frequency in MHz;

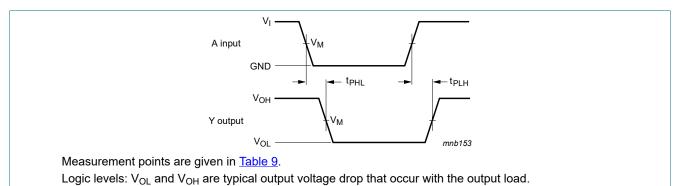
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

11.1. Waveforms and test circuit



The data input (A) to output (Y) propagation delays Fig. 6.

Table 9. Measurement points

Supply voltage	Output	Input				
	V _M	V _M	VI	t _r = t _f		
1.1 V to 3.6 V	$0.5 \times V_{CC(Y)}$	$0.5 \times V_{CC(A)}$	V _{CC(A)}	≤ 3.0 ns		

Low-power dual supply translating buffer

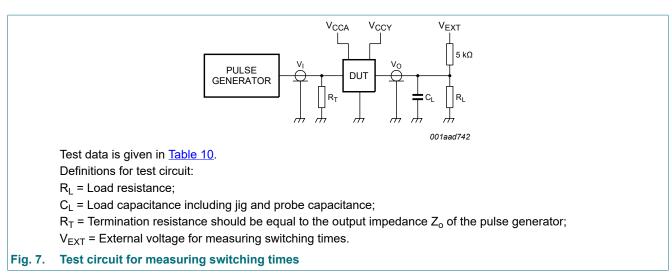


Table 10. Test data

Supply voltage	Load	V _{EXT}	
V _{CC(A)} /V _{CC(Y)}	CL	R _L [1]	t _{PLH} , t _{PHL}
1.1 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open

[1] For measuring enable and disable times $R_L = 5 k\Omega$.

For measuring propagation delays, setup and hold times and pulse width R_L = 1 M Ω .

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12. Package outline

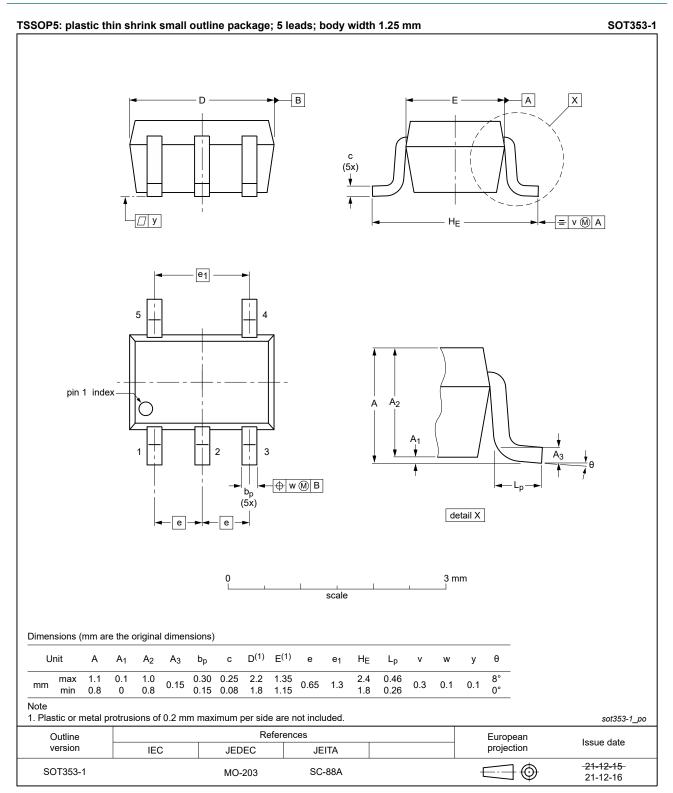


Fig. 8. Package outline SOT353-1 (TSSOP5)

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Low-power dual supply translating buffer

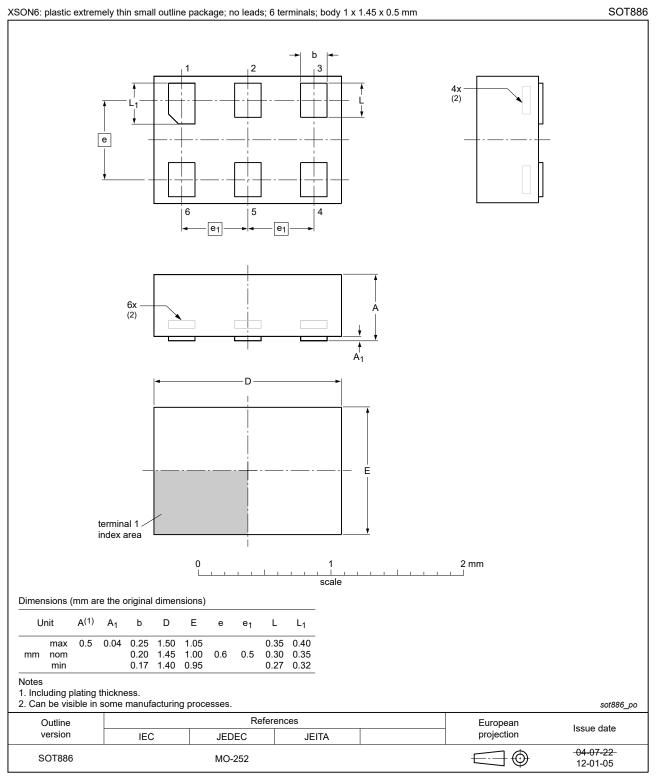


Fig. 9. Package outline SOT886 (XSON6)

13. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MIL	Military
MM	Machine Model

14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes				
74AUP1T34_Q100 v.4	20220125	Product data sheet	-	74AUP1T34_Q100 v.3				
Modifications:	 <u>Section 2</u> u <u>Fig. 8</u>: Pack 	pdated. kage outline drawing for S	SOT353-1 has chang	ed.				
74AUP1T34_Q100 v.3	20210518	Product data sheet	-	74AUP1T34_Q100 v.2				
Modifications:	 <u>Section 1</u> u <u>Table 5</u>: De 	pdated. rating values for P _{tot} total	power dissipation u	odated.				
74AUP1T34_Q100 v.2	20190128	Product data sheet	-	74AUP1T34_Q100 v.1				
Modifications:	of Nexperia • Legal texts	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Type number 74AUP1T34GM-Q100 (SOT886) added. 						
74AUP1T34_Q100 v.1	20130605	Product data sheet	-	-				

Product data sheet

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

Definitions

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Product data sheet